

## HS4040xAQx Series

**AUTOMOTIVE GRADE**

**RoHS**



### Description

The HS4040xAQx series of SCRs offer fast turn-off time (tq) characteristics required for applications such as power inverters, switching regulator, and high frequency pulse circuits.

These fast turn-off time SCRs offer high dv/dt and high di/dt characteristics required in higher frequency (>1000 PPS) switching circuits and a higher temperature environment.

### Features & Benefits

- RoHS compliant
- Voltage capability up to 400 V
- Surge capability up to 520 A
- TO-220 and TO-263 packages
- AEC-Q101 Fully compliant
- 150°C maximum junction temperature

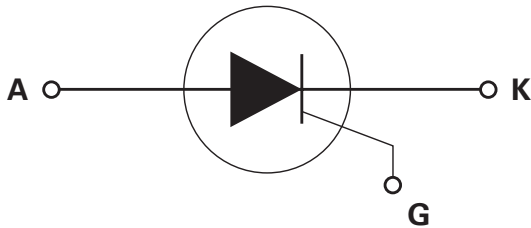
### Applications

Fast turn-off time SCRs are ideal for multi phase voltage regulator circuits, DC/AC inverters, and higher frequency pulsing power supplies.

### Main Features

| Symbol            | Value    | Unit |
|-------------------|----------|------|
| $I_{T(RMS)}$      | 40       | A    |
| $V_{DRM}/V_{RRM}$ | 400      | V    |
| $I_{GT}$          | 15 to 65 | mA   |

### Schematic Symbol



### Absolute Maximum Ratings

| Symbol            | Parameter                                 | Test Conditions                                     | Value      | Unit             |
|-------------------|---|---|------------|------------------|
| $I_{T(RMS)}$      | RMS on-state current                      | $T_c = 115^\circ\text{C}$                           | 40         | A                |
| $I_{T(AV)}$       | Average on-state current                  | $T_c = 115^\circ\text{C}$                           | 25.0       | A                |
| $I_{TSM}$         | Peak non-repetitive surge current         | single half cycle; f = 50Hz; $T_j$ (initial) = 25°C | 430        | A                |
|                   |   | single half cycle; f = 60Hz; $T_j$ (initial) = 25°C | 520        |                  |
| $I^2t$            | $I^2t$ Value for fusing                   | $t_p = 8.3$ ms                                      | 1122       | A <sup>2</sup> s |
| di/dt             | Critical rate of rise of on-state current | f = 60Hz; $T_j = 150^\circ\text{C}$                 | 175        | A/μs             |
| $I_{GM}$          | Peak gate current                         | $T_j = 150^\circ\text{C}$                           | 3.5        | A                |
| $P_{G(AV)}$       | Average gate power dissipation            | $T_j = 150^\circ\text{C}$                           | 0.8        | W                |
| $T_{stg}$         | Storage temperature range                 |   | -40 to 150 | °C               |
| $T_j$             | Operating junction temperature range      |   | -40 to 150 | °C               |
| $V_{DSM}/V_{RSM}$ | Peak non-repetitive blocking voltage      | Pw=100 μs   | 500        | V                |

**Electrical Characteristics (T<sub>J</sub> = 25°C, unless otherwise specified)**

| Symbol          | Test Conditions  |      | HS4040xAQ | HS4040xAQ2 | HS4040xAQ3 | Unit |
|-----------------|--|------|-----------|------------|------------|------|
| I <sub>GT</sub> | V <sub>D</sub> = 12V; R <sub>L</sub> = 30 Ω  | MAX. | 35        | 45         | 65         | mA   |
|                 |  | MIN. | 15        | 30         | 38         |      |
| V <sub>GT</sub> |  | MAX. | 1.5       |            |            | V    |
| I <sub>GT</sub> | V <sub>D</sub> = 12V; R <sub>L</sub> = 30Ω; T <sub>J</sub> = -40°C                   | MAX. | 75        | 95         | 160        | mA   |
| dv/dt           | V <sub>D</sub> = V <sub>DRM'</sub> ; gate open; T <sub>J</sub> = 150°C               | MIN. | 550       |            |            | V/μs |
| V <sub>GD</sub> | V <sub>D</sub> = V <sub>DRM'</sub> ; R <sub>L</sub> = 3.3 kΩ; T <sub>J</sub> = 150°C | MIN. | 0.2       |            |            | V    |
| I <sub>H</sub>  | I <sub>T</sub> = 400mA (initial)   | MAX. | 70        | 120        | 200        | mA   |
| t <sub>q</sub>  | I <sub>T</sub> =0.5A; t <sub>p</sub> =50μs; dv/dt=5V/μs; di/dt=-30A/μs               | MAX. | 15        | 12         | 5          | μs   |
| t <sub>gt</sub> | I <sub>G</sub> = 2 x I <sub>GT</sub> ; PW = 15μs; I <sub>T</sub> = 80A               | TYP. | 3.0       |            |            | μs   |

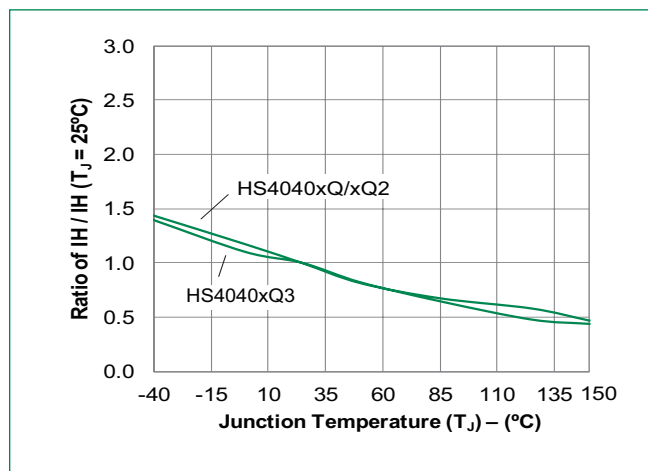
**Static Characteristics**

| Symbol                              | Test Conditions                              |                        | HS4040xAQ | HS4040xAQ2 | HS4040xAQ3 | Unit |
|-------------------------------------|--|------------------------|-----------|------------|------------|------|
| V <sub>TM</sub>                     | I <sub>T</sub> = 80A; t <sub>p</sub> = 380μs | MAX.                   | 1.6       |            | 1.8        | V    |
| I <sub>DRM</sub> / I <sub>RRM</sub> | V <sub>DRM</sub> / V <sub>RRM</sub>          | T <sub>J</sub> = 25°C  | 10        |            |            | μA   |
|                                     |  | T <sub>J</sub> = 125°C | 2000      |            |            |      |
|                                     |  | T <sub>J</sub> = 150°C | 4000      |            |            |      |

**Thermal Resistances**

| Symbol              | Parameter             | Value | Unit |
|---------------------|-----------------------|-------|------|
| R <sub>θ(J-C)</sub> | Junction to case (AC) | 0.6   | °C/W |

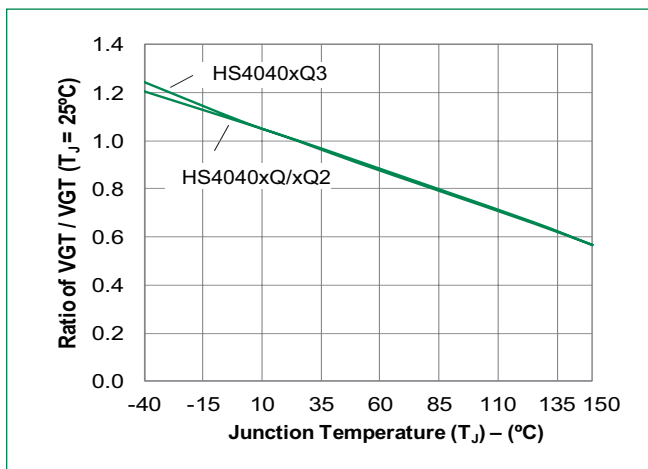
**Figure 1: Normalized DC Holding Current vs. Junction Temperature**



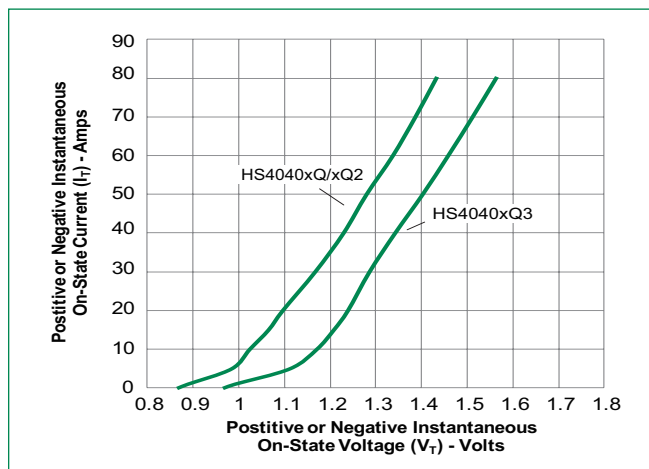
**Figure 2: Normalized DC Gate Trigger Current vs. Junction Temperature**



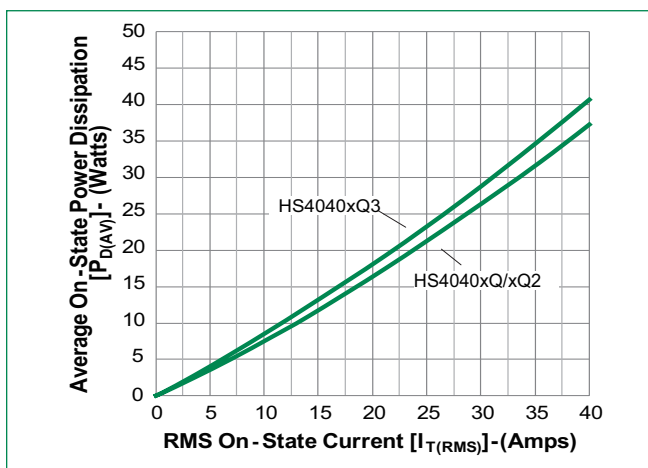
**Figure 3: Normalized DC Gate Trigger Voltage vs. Junction Temperature**



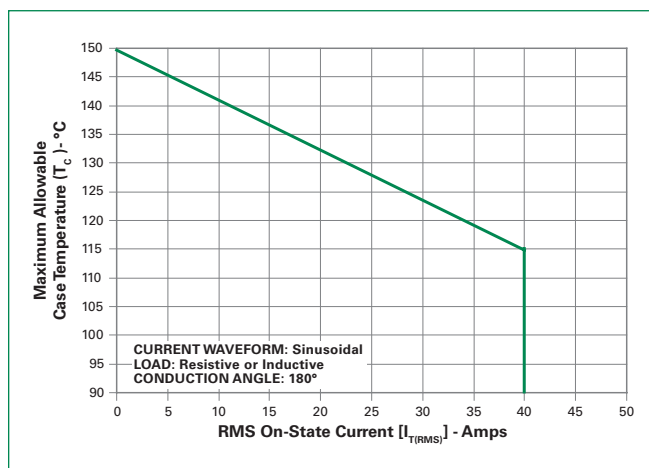
**Figure 4: On-State Current vs. On-State Voltage (Typical)**



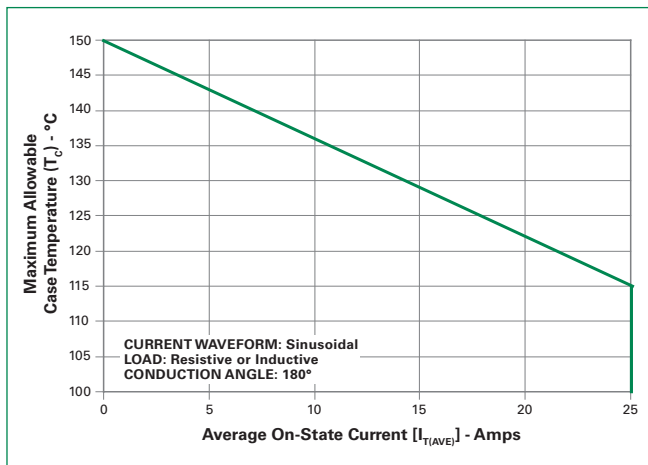
**Figure 5: Power Dissipation (Typical) vs. RMS On-State Current**



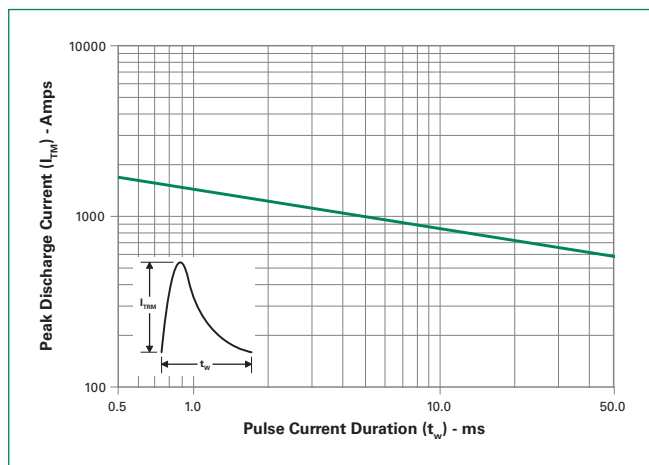
**Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current**



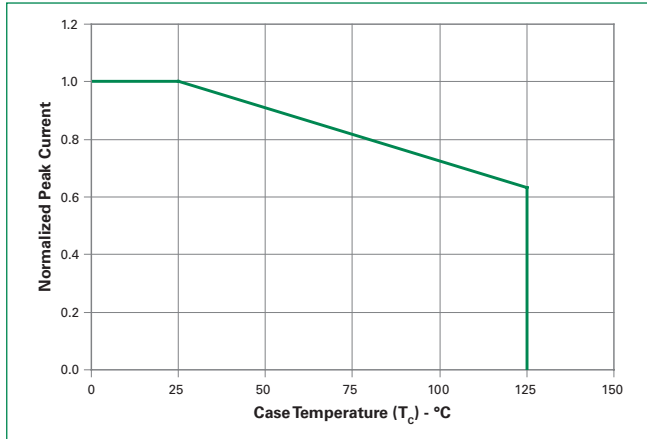
**Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current**



**Figure 8: Peak Capacitor Discharge Current**



**Figure 9: Peak Capacitor Discharge Current Derating**



**Figure 10: Surge Peak On-State Current vs. Number of Cycles**

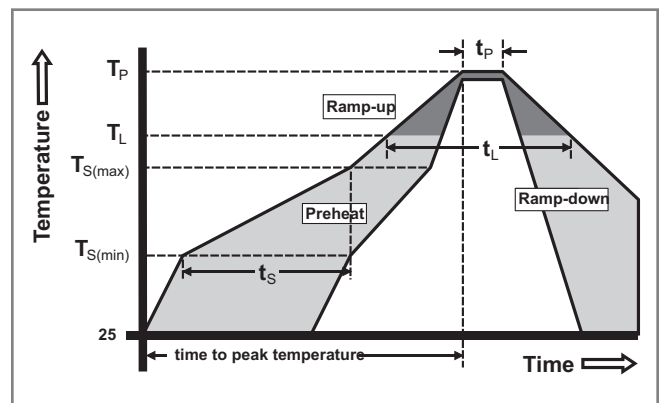


SUPPLY FREQUENCY: 60 Hz Sinusoidal  
LOAD: Resistive  
RMS On-State Current: [I<sub>T(RMS)</sub>]: Maximum Rated Value at Specified Case Temperature

Notes:  
1. Gate control may be lost during and immediately following surge current interval.  
2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

**Soldering Parameters**

|  |  |                         |
|--|--|-------------------------|
| Reflow Condition   | Pb – Free assembly                         |                         |
| Pre Heat   | - Temperature Min (T <sub>s(min)</sub> )   | 150°C                   |
|  | - Temperature Max (T <sub>s(max)</sub> )   | 200°C                   |
|  | - Time (min to max) (t <sub>s</sub> )      | 60 – 180 secs           |
| Average ramp up rate (Liquidus Temp (T <sub>L</sub> ) to peak) |  | 5°C/second max          |
| T <sub>s(max)</sub> to T <sub>L</sub> - Ramp-up Rate           |  | 5°C/second max          |
| Reflow   | - Temperature (T <sub>L</sub> ) (Liquidus) | 217°C                   |
|  | - Temperature (t <sub>L</sub> )            | 60 – 150 seconds        |
| Peak Temperature (T <sub>p</sub> )                             |  | 260 <sup>+0/-5</sup> °C |
| Time within 5°C of actual peak Temperature (t <sub>p</sub> )   |  | 20 – 40 seconds         |
| Ramp-down Rate   |  | 5°C/second max          |
| Time 25°C to peak Temperature (T <sub>p</sub> )                |  | 8 minutes Max.          |
| Do not exceed  |  | 280°C                   |



**Physical Specifications**

|                        |   |
|------------------------|---|
| <b>Terminal Finish</b> | 100% Matte Tin-plated                                       |
| <b>Body Material</b>   | UL recognized epoxy meeting flammability classification V-0 |
| <b>Lead Material</b>   | Copper Alloy  |

**Design Considerations**

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

**Environmental Specifications**

| Test                                     | Specifications and Conditions  |
|--|--|
| <b>AC Blocking</b>                       | MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 150°C for 1008 hours   |
| <b>Biased Temperature &amp; Humidity</b> | EIA / JEDEC, JESD22-A101<br>1008 hours; 320V - DC: 85°C;<br>85% rel humidity |
| <b>Temperature Cycling</b>               | JESD22 A-104 Appendix 6<br>-55°C to 150°C, 15-minute dwell,<br>1000 cycles   |
| <b>Intermittent Operational Life</b>     | T <sub>A</sub> =25C, ΔT <sub>J</sub> ≥ 100°C, 1008hrs                        |
| <b>Autoclave (Pressure Cooker Test)</b>  | EIA/JEDEC: JESD22-A102<br>121°C, 100%RH, 15psig, 96hours                     |
| <b>Resistance to Solder Heat</b>         | JESD22 A-111: 260°C, 10 seconds  |
| <b>Solderability</b>                     | ANSI/J-STD-002, category 3, Test A   |

**Dimensions — TO-220AB (R-Package) — Non-Isolated Mounting Tab Common with Center Lead**



Note: Maximum torque to be applied to mounting tab is 8 in-lbs. (0.904 Nm).

| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min    | Max   | Min         | Max   |
| A         | 0.380  | 0.420 | 9.65        | 10.67 |
| B         | 0.105  | 0.115 | 2.67        | 2.92  |
| C         | 0.230  | 0.250 | 5.84        | 6.35  |
| D         | 0.590  | 0.620 | 14.99       | 15.75 |
| E         | 0.142  | 0.147 | 3.61        | 3.73  |
| F         | 0.110  | 0.130 | 2.79        | 3.30  |
| G         | 0.540  | 0.575 | 13.72       | 14.61 |
| H         | 0.025  | 0.035 | 0.64        | 0.89  |
| J         | 0.195  | 0.205 | 4.95        | 5.21  |
| K         | 0.095  | 0.105 | 2.41        | 2.67  |
| L         | 0.060  | 0.075 | 1.52        | 1.91  |
| M         | 0.085  | 0.095 | 2.16        | 2.41  |
| N         | 0.018  | 0.024 | 0.46        | 0.61  |
| O         | 0.178  | 0.188 | 4.52        | 4.78  |
| P         | 0.045  | 0.060 | 1.14        | 1.52  |
| R         | 0.038  | 0.048 | 0.97        | 1.22  |

**Dimensions – TO- 263 (N-package) – D<sup>2</sup>-Pak Surface Mount**



| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min    | Max   | Min         | Max   |
| A         | 0.360  | 0.370 | 9.14        | 9.40  |
| B         | 0.380  | 0.420 | 9.65        | 10.67 |
| C         | 0.178  | 0.188 | 4.52        | 4.78  |
| D         | 0.025  | 0.035 | 0.63        | 0.89  |
| E         | 0.048  | 0.055 | 1.22        | 1.40  |
| F         | 0.060  | 0.075 | 1.52        | 1.91  |
| G         | 0.095  | 0.105 | 2.41        | 2.67  |
| H         | 0.083  | 0.093 | 2.11        | 2.36  |
| J         | 0.018  | 0.024 | 0.46        | 0.61  |
| K         | 0.090  | 0.110 | 2.29        | 2.79  |
| S         | 0.590  | 0.625 | 14.99       | 15.87 |
| V         | 0.035  | 0.045 | 0.89        | 1.14  |
| U         | 0.002  | 0.010 | 0.05        | 0.25  |
| W         | 0.040  | 0.070 | 1.02        | 1.78  |

**Part Numbering System**



**Part Marking System**

TO-220 AB - (R Package)  
TO-263 (N Package)



**Date Code Marking**  
Y: Year Code  
M: Month Code  
XXX: Lot Trace Code

**Product Selector**

| Part Number | Voltage | Gate Sensitivity | Type         | Package  |
|-------------|---------|------------------|--------------|----------|
|             | 400V    |                  |              |          |
| HS4040RAQ   | X       | 15-35            | Standard SCR | TO-220AB |
| HS4040NAQ   | X       | 15-35            | Standard SCR | TO-263   |
| HS4040RAQ2  | X       | 30-45            | Standard SCR | TO-220AB |
| HS4040NAQ2  | X       | 30-45            | Standard SCR | TO-263   |
| HS4040RAQ3  | X       | 38-65            | Standard SCR | TO-220AB |
| HS4040NAQ3  | X       | 38-65            | Standard SCR | TO-263   |

**Packing Options**

| Part Number  | Marking    | Weight | Packing Mode     | Base Quantity     |
|--------------|------------|--------|------------------|-------------------|
| HS4040RAQTP  | HS4040RAQ  | 2.2g   | Tube             | 500 (50 per tube) |
| HS4040RAQ2TP | HS4040RAQ2 | 2.2g   | Tube             | 500 (50 per tube) |
| HS4040RAQ3TP | HS4040RAQ3 | 2.2g   | Tube             | 500 (50 per tube) |
| HS4040NAQRP  | HS4040NAQ  | 1.6g   | Embossed Carrier | 500               |
| HS4040NAQ2RP | HS4040NAQ2 | 1.6g   | Embossed Carrier | 500               |
| HS4040NAQ3RP | HS4040NAQ3 | 1.6g   | Embossed Carrier | 500               |

**Reel Pack (RP) for TO-263 Embossed Carrier Specifications**

Meets all EIA-481-2 Standards

